

## Circuit Design of On-Chip BP Learning Neural Network with Programmable Neuron Characteristics<sup>\*</sup>

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**Abstract:** A circuit system of on-chip BP(Back-Propagation) learning neural network with programmable neurons has been designed, which comprises a feedforward network, an error back-propagation network and a weight updating circuit. It has the merits of simplicity, programmability, speediness, low power-consumption and high density. A novel neuron circuit with programmable parameters has been proposed. It generates not only the sigmoidal function but also its derivative. HSPICE simulations are done to a neuron circuit with level 47 transistor models as a standard 1.2 $\mu$ m CMOS process. The results show that both functions are matched with their respective ideal functions very well. The non-linear partition problem is used to verify the operation of the network. The simulation result shows the superior performance of this BP neural network with on-chip learning.

**Key words:** hardware implementation of neural networks; CMOS analogue integrated circuits; programmability

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### 1 Introduction

Artificial neural networks with a Back-Propagation (BP) algorithm present a practical approach to various problems. The hardware implementation is very necessary and essential because of the normal requirements of many applications. Hardware implementation of BP neural networks can be achieved in several ways, including off-chip learning, chip-in-the-loop learning and on-chip learning. Which one to be chosen is not always clear-cut in practice, and the answer depends on not only the application, but also the topology of a net-

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work and its different constraints as well. On-chip learning is imperative if the system meets the following requirements<sup>[1-5]</sup>: (1) high speed, (2) autonomous operation in an unknown and changing environment, (3) small volume, (4) reduced weight.

One of the neural networks' important components is the neuron, whose performance and complexity greatly affect the whole net. In many literatures, its activation function is found to be sigmoid. In the on-chip back-propagation learning, the non-linear function and its derivative are both required. A simple neuron circuit<sup>[6]</sup>, which can realize both the neuron activation function and its derivative, has been proposed in this paper. Having current inputs and voltage outputs, the neuron is built with strong-inversion biased transistors. Furthermore, the circuit enables the threshold and the gain factor to be adjustable.

## 2 Circuit System Architecture

The BP network includes the input layer, the hidden layer(s) and the output layer. Each layer has several neurons. The transfer function of each neuron is always a sigmoid one as expressed in Eq. 1,

$$f(S) = \frac{1}{1 + \exp(-\alpha(S) + \theta)} \quad (1)$$

where  $S = X \cdot W$ ,  $X$  is the input matrix,  $W$  is the weight matrix,  $\alpha$  is the gain factor and  $\theta$  is the threshold vector. It is supposed that  $R$  is the number of the training set elements,  $w_{ij}^l$  is the weight between the  $i$ th ( $0 \leq i < n$ ) neuron of the  $(l-1)$ th layer and the  $j$ th neuron of the  $l$ th ( $l = 1, 2, \dots, L$ ) layer, and  $\theta_j^l$  is the threshold of the  $j$ th neuron of the  $l$ th layer. For the sake of convenience, let  $\theta_j^l = w_{nj}^l$  and  $x_n^{l-1} = 1$ . To a certain training sample  $r$  ( $r = 1, 2, \dots, R$ ),  $x_{i,r}^{l-1}$  is the output of the  $i$ th neuron of the  $(l-1)$ th layer;  $x_{j,r}^l$  is that of the  $j$ th neuron of the  $l$ th layer;  $t_{j,r}$  is the target value when  $l = L$ ;  $s_{j,r}^l$  is the weighted sum from the  $i$ th neurons of the  $(l-1)$ th layer to the  $j$ th neuron of the  $l$ th layer. The feedforward calculation can be expressed as follows,

$$x_{j,r}^l(k) = f(s_{j,r}^l(k)) = f\left[\sum_{i=0}^n w_{ij}^l(k) x_{i,r}^{l-1}(k)\right] \quad (2)$$

To describe the error back-propagation process, several definition should be made first. The neuron error is defined as,

$$\epsilon_{ij,r}^l(k) = \begin{cases} t_{j,r} - x_{j,r}^l(k), & l = L \\ \sum_j w_{ij}^{l+1}(k) \delta_{j,r}^{l+1}(k), & 1 \leq l < L \end{cases} \quad (3)$$

where the weight error is defined as,

$$\delta_{ij,r}^l(k) = f'(s_{i,r}^l(k)) \epsilon_{ij,r}^l(k) \quad (4)$$

Then the weight updating rule can be expressed as Equation (5),

$$w_{ij}^l(k+1) = w_{ij}^l(k) + \eta \sum_{r=1}^R \delta_{ij,r}^l(k) x_{j,r}^l(k) \quad (5)$$

where  $\eta$  is the learning rate,  $\Delta w_{ij}^l(k+1) = \sum_{r=1}^R \delta_{ij,r}^l(k) x_{j,r}^l(k)$  is the weight change.

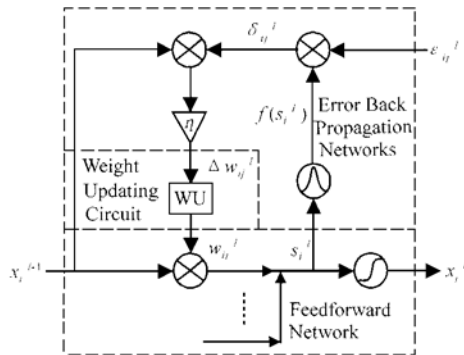


FIG. 1 Diagram of Circuit System

Weight Unit (WU) implements the weight update operation, with the diagram shown in Fig. 2. A 7-bit ADC is used to convert the analog weight change signal to a digital one and is added to the 12-bit weight. The new weight is converted to an analog signal by a DAC for the next feedforward calculation and stored in the RAM for the next weight updating.

The circuit system is designed according to the algorithm above. It comprises a feedforward network, an error back-propagation network and a weight updating circuit, as shown in Figure 1. In the feedforward network, the synapse is realized by the Gilbert multiplier, as is simple and area-economic. The nonlinear  $I$ - $V$  transfer function is achieved by the neuron. Using the forward difference method, the neuron generates a sigmoidal function with its derivative. The latter is used in the error back-propagation network. The

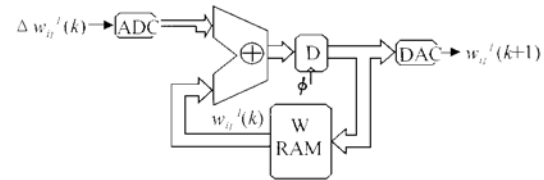


FIG. 2 Diagram of Weight Updating Unit

### 3 Neuron Circuit

Figure 3(a) shows the schematic diagram of the proposed neuron circuit.  $V_{dd}$  is the 3.3V-voltage source.  $V_{out1}$  outputs the sigmoidal activation function. The approximate derivative can be obtained via  $(V_{out1} - V_{out2})$ . In the dash frame, the fixed voltage  $V_{ref1}$  is carefully chosen so that both the transistors M1 and M2 work in their respective linear ranges. The formed linear resistor  $R_{AB}$  can be controlled by the gate voltage of both transistors  $V_N$  and  $V_P$ . In the dash dot frame, a simple differential pair composed of identical transistors and the active loads makes the actual sigmoidal non-linear. One port of the differential pair is connected to point B and the other to a fixed voltage  $V_{ref2}$  or  $V_{ref2} - \Delta V$ , where  $\Delta V$  is a small fixed voltage.  $I_{ref1}$  and  $I_{ref2}$  are the fixed current sources.

Assuming that M3, M4 operate in saturation and follow the ideal square law, we have

$$I_{ref} = \frac{\beta}{2} [(V_B - V_C)^2 + (V_D - V_C)^2] \quad (6)$$

where  $\beta$  is the transconductance parameter for the transistors M3 and M4. The voltage of point C can be obtained from Eq. 7.

$$V_C = \frac{(V_B + V_D) - \sqrt{\frac{4I_{ref2}}{\beta} - (V_B - V_D)^2}}{2} \quad (7)$$



The great power of an artificial neural network derives from its adaptability to the unknown and changing environment. Therefore, good programmability is of the fundamental importance<sup>[8,9]</sup>. Different application need different gain factor  $\alpha$  and threshold vector  $\theta$ , which can be obtained by varying  $I_{ref1}$ ,  $V_N$  and  $V_P$ .

The threshold vector  $\theta$  can be adjusted by changing the reference current  $I_{ref1}$ . When  $I_{ref1}$  increases, the current  $I_{in}$  will decrease, which is needed to satisfy that  $V_B - V_{ref2} > \sqrt{2I_{ref2}/\beta}$  so that the activation curve will shift to the left. Otherwise, it will shift to the right. Figure 4(a) shows the simulated neuron transfer functions with different thresholds.

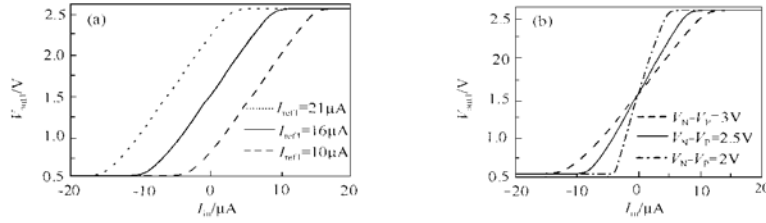


FIG. 4 Programmability of Neuron

(a) Transfer Curve with Different Thresholds, (b) Transfer Curves with Different Gain Factors

The gain factor  $\alpha$  can be varied by changing the control voltages  $V_N$  and  $V_P$ . When both transistors M1 and M2 are working in their respective linear ranges and their sizes are chosen as  $\beta_1 = \beta_2$ , the relation between  $I_{AB}$  and  $V_{AB}$  can be written as

$$I_{AB} = I_1 + I_2 = \beta_1 V_{AB} [(V_N - V_{T1}) - (V_P + |V_{T2}|)] \quad (11)$$

so the equivalent linear resistor  $R_{AB}$  is written as

$$R_{AB} = \frac{1}{\beta_1 [(V_N - V_P) - (V_{T1} + |V_{T2}|)]} \quad (12)$$

Equation (12) shows that the bigger  $(V_N - V_P)$  is, the less  $R_{AB}$  would be, i. e. the less the slope of  $V_B$  versus  $I_{in}$  would be. Should the  $V_{out1}$  increase more slowly, the gain factor would be smaller. Different activation functions with various gain factors are shown in Fig. 4(b). Note that the saturation levels of the sigmoid remain constant for different gain values, in contrast to most of the implementations reported in literatures<sup>[7]</sup>. This ensures that for different gain values, the input linear range of the synapse in subsequent layer can be fully used.

## 4 Experiment Results

The non-linear partition problem is used to verify the operation of the proposed circuit system with 2-I configuration. Figure 5 illustrates the transient output of the training. Considered that the low output voltage of the neuron is 0.52V, the high output voltage is 2.59V and the middle voltage is 1.56V, the experiment can be described as follows: if the

two inputs are both lower than 1.56V or both greater than 1.56V, the output is 2.59V; otherwise, it is 1.56V. The corresponding inputs of linear *A*, *B*, *C* and *D* in Fig. 4 are (1V, 1V), (1V, 2V), (2V, 1V), (2V, 2V) respectively and the corresponding targets are 0.52, 2.59, 2.59 and 0.52V respectively. It can be seen from Fig. 5 that the circuit system converges within 1ms.

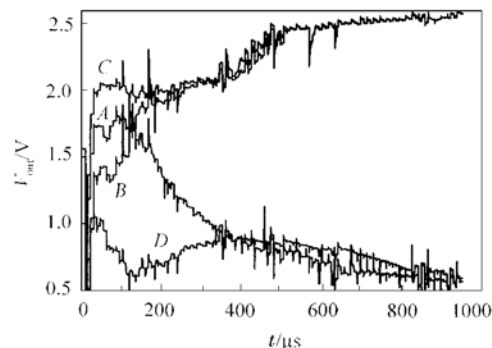


FIG. 5 Transient Output Curves of Non-Linear Partition Problem

## 5 Conclusions

A circuit system of programmable BP on-chip learning neural network has been designed with analog circuits except the weight storage unit. It has the merits of simplicity, speediness, low power-consumption and high density. The whole system comprises a feedforward network, an error back-propagation network and a weight updating circuit. A novel programmable neuron has been proposed, which generates the sigmoidal function and its derivative using the forward differential method. With level 47 transistor models as a standard 1.2μm CMOS process, HSPICE simulations are done to the neuron. The results show that the relative error between the generated neuron activation function and its fitted sigmoid function is less than 3% and that between the derivatives observed from the simulation and the simulated neuron activation function is less than 5%. Moreover, the threshold and the gain factor of the neuron can be easily programmed according to different requirements. The simulation of the non-linear partition problem verifies the superior performance of this BP neural network with on-chip learning.

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